
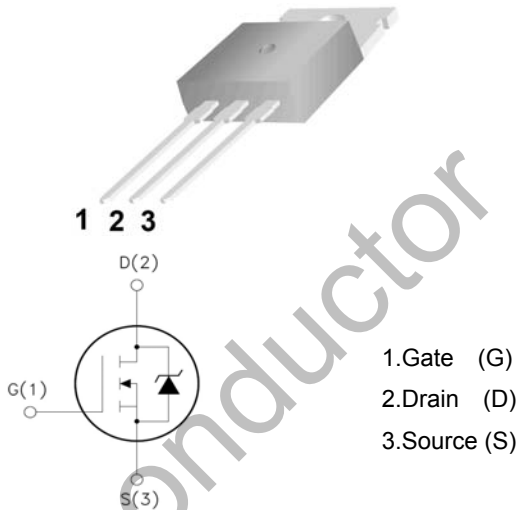


WGP20N60J

Features:

- Low Intrinsic Capacitances.
- Excellent Switching Characteristics.
- Extended Safe Operating Area.
- Unrivalled Gate Charge :Qg=75 nC (Typ.).
- BVDSS=600V, I_D=20A
- R_{DS(on)} : 0.18Ω (Max) @V_G=10V
- 100% Avalanche Tested

TO-220 



1.Gate (G)
2.Drain (D)
3.Source (S)

Absolute Maximum Ratings (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{DSS}	Drain-Source Voltage	600	V
I _D	Drain Current	T _C =25°C	20
		T _C =100°C	12.6
V _{GSS}	Gate-Source Voltage	±30	V
E _{AS}	Single Pulse Avalanche Energy (note1)	690	mJ
I _{AR}	Avalanche Current (note2)	20	A
P _D	Power Dissipation (Tc=25°C)	126	W
T _j	Junction Temperature(Max)	150	°C
T _{stg}	Storage Temperature	-55~+150	
TL	Maximum lead temperature for soldering purpose, 1/8" from case for 5 seconds	300	

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
R _{θJC}	Thermal Resistance, Junction to Case	-	3.2	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	-	62.5	

Electrical Characteristics (Ta=25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Off Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	I _D =250μA, V _{GS} =0	600	-	-	V
ΔBV _{DSS} /ΔT _J	Breakdown Voltage Temperature Coefficient	I _D =250μA, Reference to 25°C	-	0.71	-	V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =600V, V _{GS} =0V V _{DS} =480V, T _C =125°C	-	-	10 100	μA
I _{GSSF}	Gate-body leakage Current, Forward	V _{GS} =+30V, V _{DS} =0V	-	-	100	nA
I _{GSSR}	Gate-body leakage Current, Reverse	V _{GS} =-30V, V _{DS} =0V	-	-	-100	nA
On Characteristics						
V _{GS(TH)}	Gate Threshold Voltage	I _D =250μA, V _{DS} =V _{GS}	2	-	4	V
R _{DS(ON)}	Static Drain-Source On-Resistance	I _D =10A, V _{GS} =10V	-	0.15	0.19	Ω
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{DS} =25V, V _{GS} =0, f=1.0MHz	-	2370	3080	pF
C _{oss}	Output Capacitance		-	1280	1665	
C _{rss}	Reverse Transfer Capacitance		-	95	-	
Switching Characteristics						
T _{d(on)}	Turn-On Delay Time	V _{DD} =300V, I _D =20A R _G =25Ω (Note 3,4)	-	62	135	ns
T _r	Turn-On Rise Time		-	140	290	
T _{d(off)}	Turn-Off Delay Time		-	230	470	
T _f	Turn-Off Rise Time		-	65	140	
Q _g	Total Gate Charge	V _{DS} =480V, V _{GS} =10V, I _D =20A (Note 3,4)	-	75	98	nC
Q _{gs}	Gate-Source Charge		-	13	-	
Q _{gd}	Gate-Drain Charge		-	36	-	
Drain-Source Diode Characteristics and Maximum Ratings						
I _S	Max. Diode Forward Current	-	-	-	20	A
I _{SM}	Max. Pulsed Forward Current	-	-	-	60	A
V _{SD}	Diode Forward Voltage	I _D =20A	-	-	1.4	V
T _{rr}	Reverse Recovery Time	I _S =20A, V _{GS} =0V diF/dt=100A/μs	530	-	-	ns
Q _{rr}	Reverse Recovery Charge	(Note3)	3.69	-	-	μC

- Notes : 1, L=3.45mH, I_{AS}=20A, V_{DD}=50V, R_G=25Ω, Starting T_J=25°C
 2, Repetitive Rating : Pulse width limited by maximum junction temperature
 3, Pulse Test : Pulse Width ≤ 300μs, Duty Cycle ≤ 2%
 4, Essentially Independent of Operating Temperature

Typical Characteristics

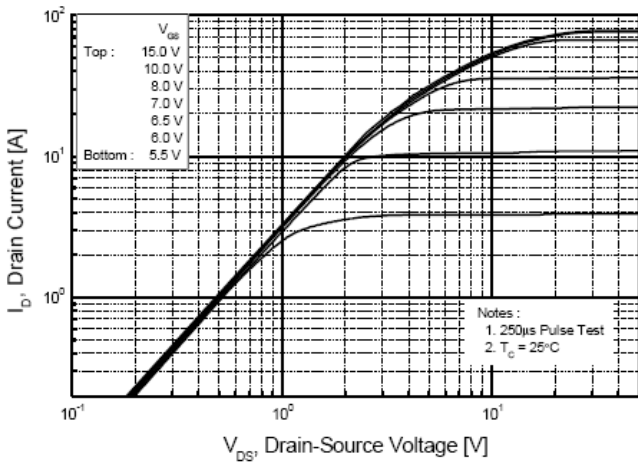


Fig. 1. On-Region Characteristics

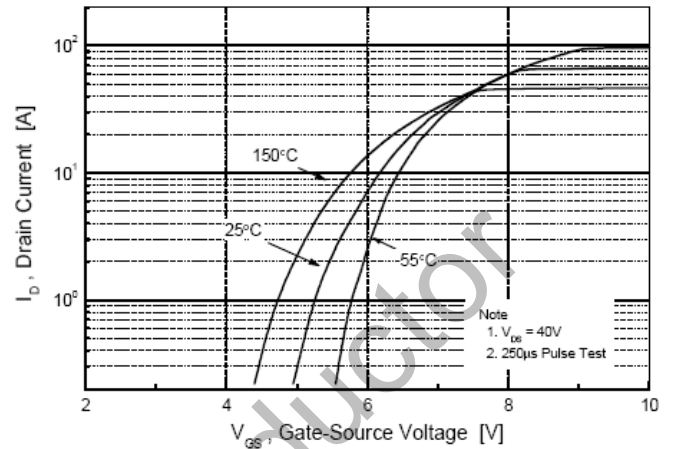


Fig. 2. Transfer Characteristics

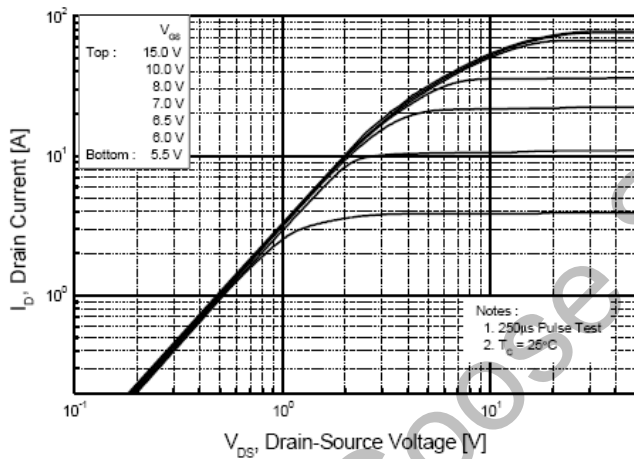


Fig. 3. On-Resistance Variation vs Drain Current and Gate Voltage

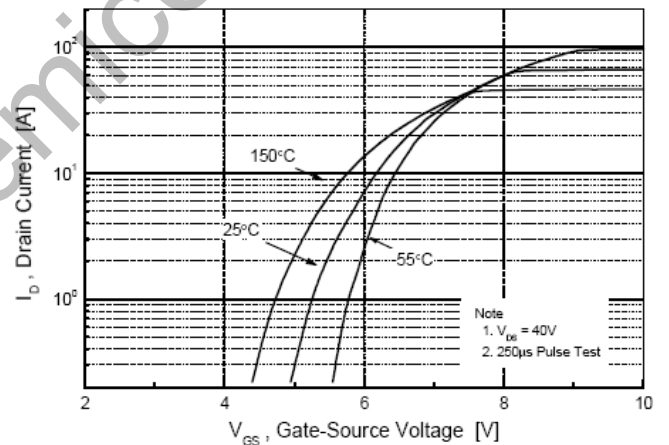


Fig. 4. Body Diode Forward Voltage Variation with Source Current and Temperature

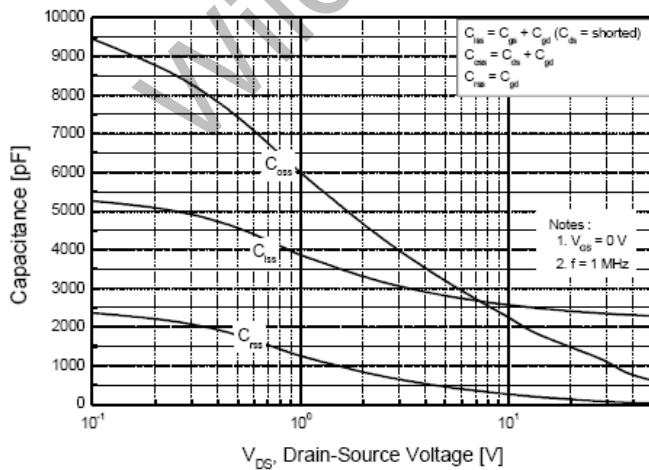


Fig. 5. Capacitance Characteristics

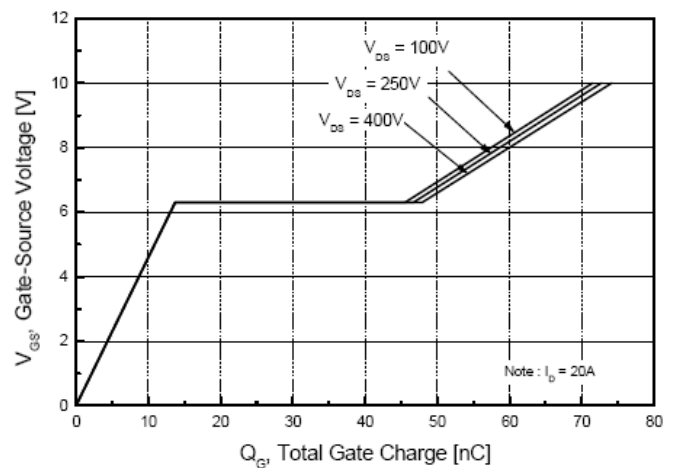


Fig. 6. Gate Charge Characteristics

Typical Characteristics (Continued)

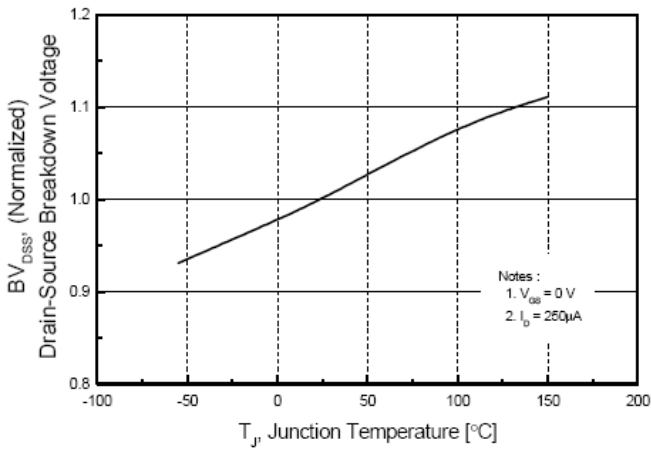


Fig. 7. Breakdown Voltage Variation vs Temperature

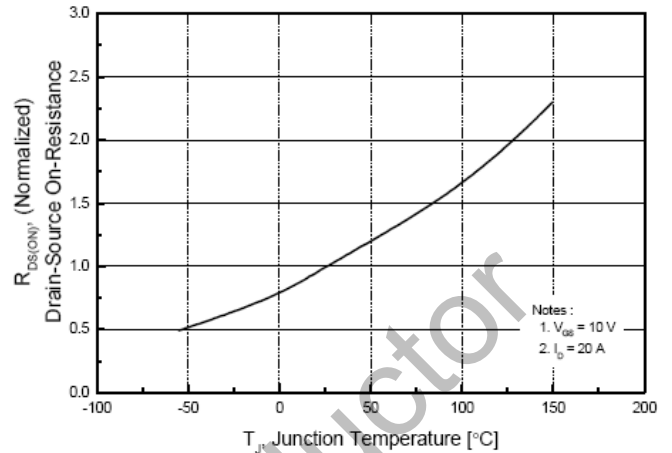


Fig. 8. On-Resistance Variation vs Temperature

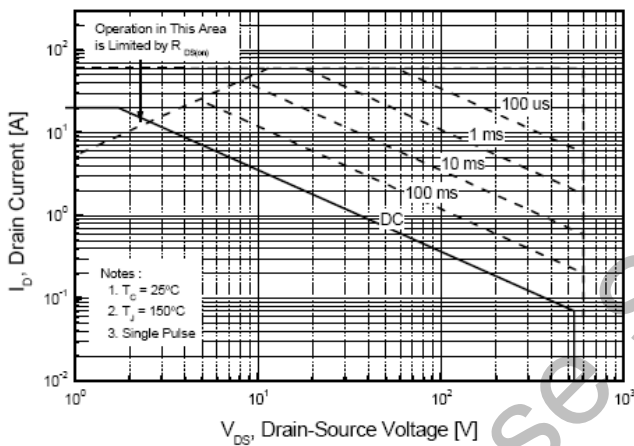


Fig. 9. Maximum Safe Operating Area

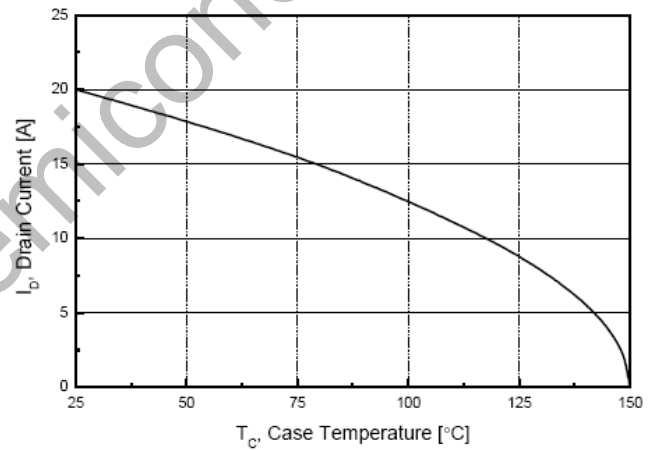


Fig. 10. Maximum Drain Current vs Case Temperature

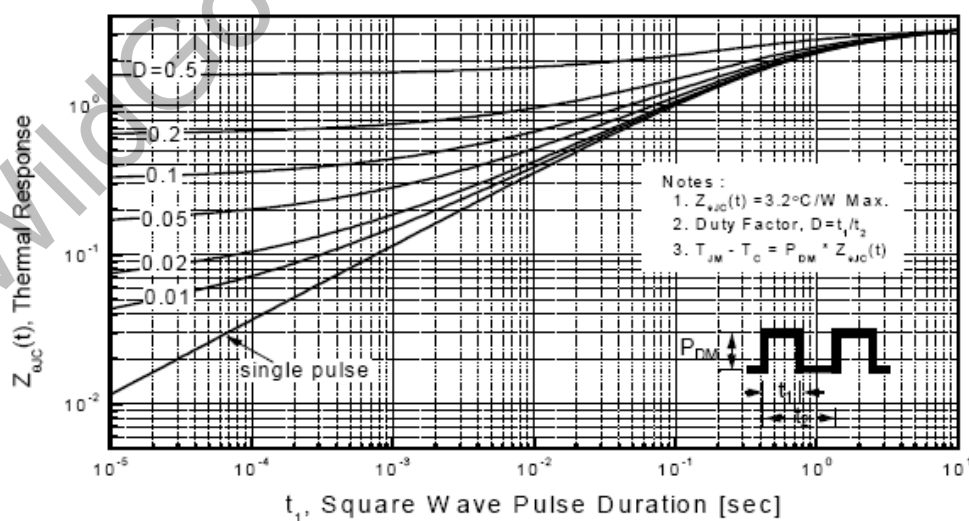
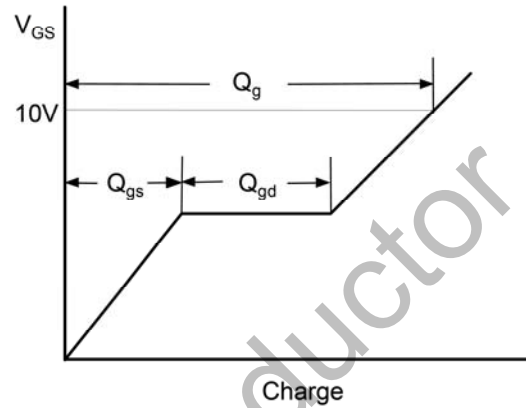
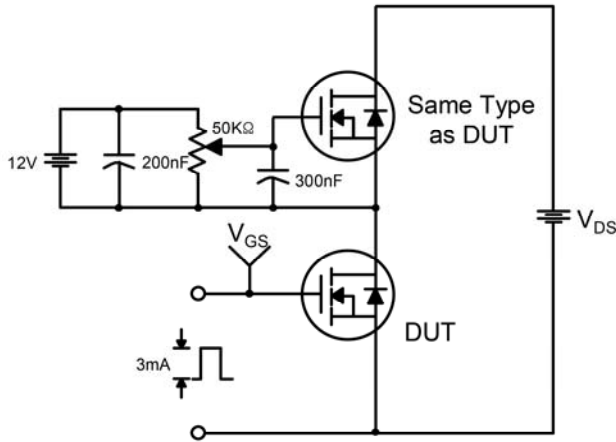
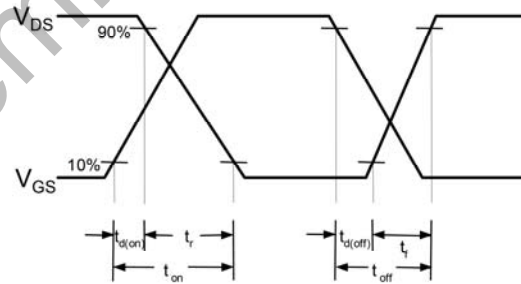
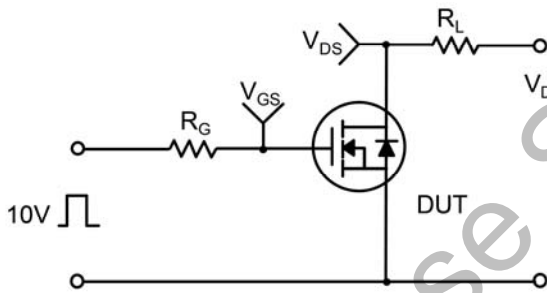


Fig 11. Transient Thermal Response Curve

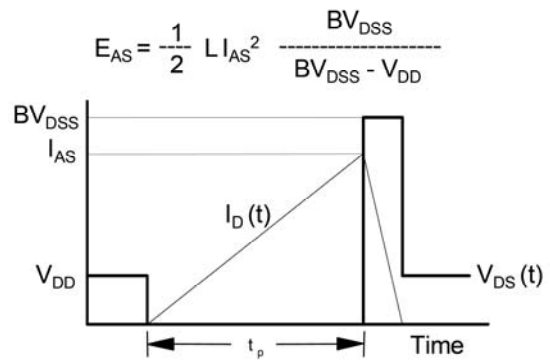
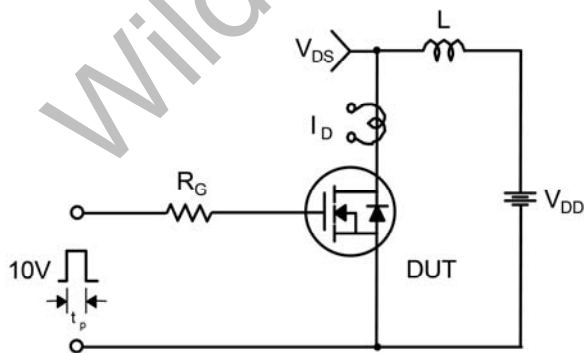
Gate Charge Test Circuit & Waveform



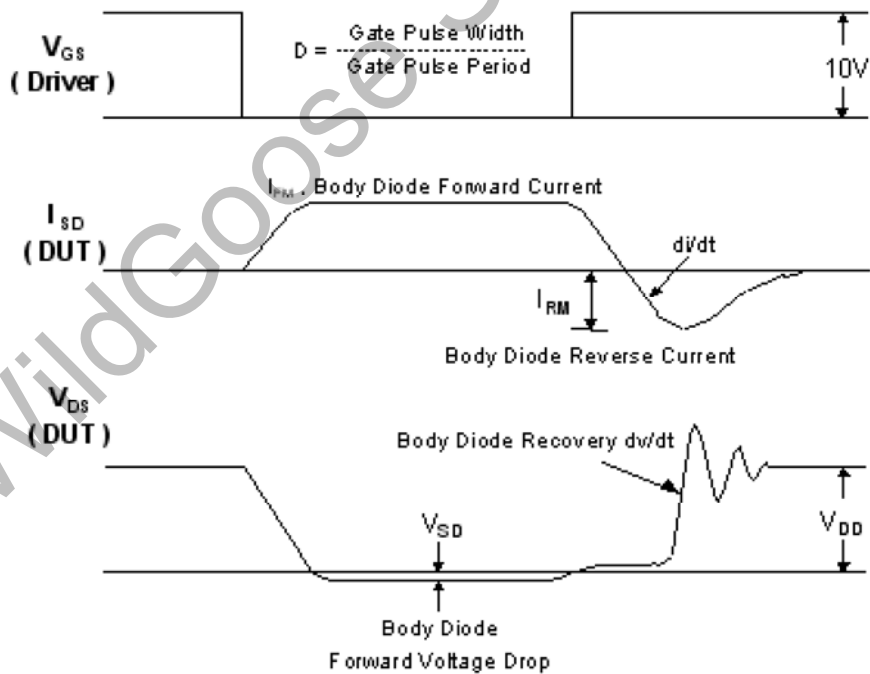
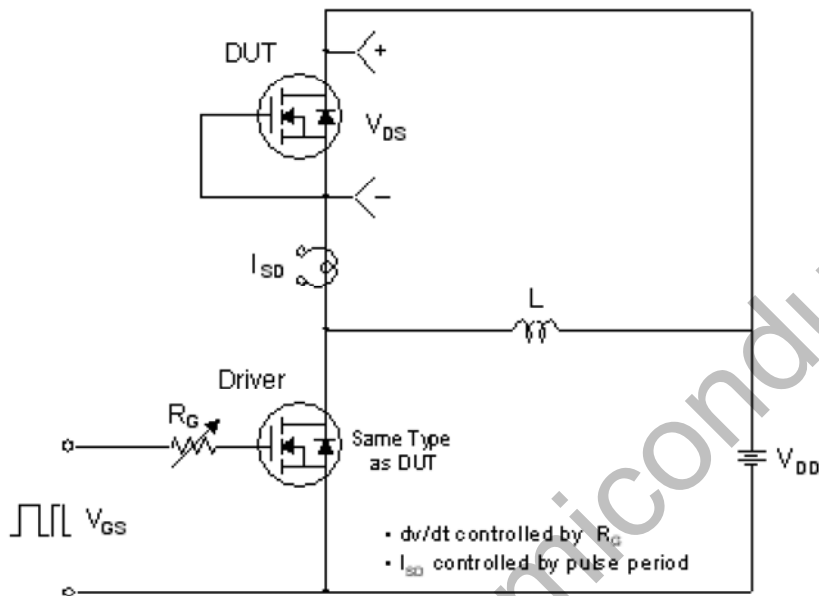
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms



Peak Diode Recovery dv/dt Test Circuit & Waveform



Package Dimension

TO-220

Unit: mm

